



A-70028-2/MSS/TJH
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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

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0028-2/MSS/TJH

INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				<i>Complete if Known</i>	
Sheet	1	of	2	Application Number	10/766,148
				Filing Date	January 27, 2004
				First Named Inventor	Yoshihide SENZAKI
				Group Art Unit	Not yet assigned
				Examiner Name	Not yet assigned
				Attorney Docket Number	A-70028-2/MSS/TJH

U.S. PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS

***EXAMINER:** Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Unique citation designation number. ² See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁶ Applicant is to place a check mark here if English Language Translation is attached.

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OTHER PRIOR ART - NON PATENT LITERATURE DOCUMENTS						
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.				T ²
PC	C1	MANCHANDA et al., "Si-Doped Aluminates for High Temperature Metal-Gate CMOS: Zr-Al-Si-O, A Novel Gate Dielectric for Low Power Applications, 2000 IEEE, pp. 15-18.				
PC	C2	WILK et al., "Electrical Properties of Hafnium Silicate Gate Dielectrics Deposited Directly on Silicon", <i>Applied Physics Letter</i> , vol. 74, 1999, pp. 2854-2856.				
PC	C3	WILK et al., "Stable Zirconium Silicate Gate Dielectrics Deposited Directly on Silicon", <i>Applied Physics Letters</i> , vol. 76, no. 1, January 3, 2000, pp. 112-114.				
PC	C4	WOLFE, D., et al., "Remote Plasma Enhanced-Metal Organic Chemical Vapor Deposition of Zirconium Oxide/ Silicon Oxide Alloy, $(\text{ZrO}_2)_x(\text{SiO}_2)_{1-x}$ ($x \leq 0.5$), Thin Films for Advanced High-K Gate Dielectrics", <i>Materials Research Society Symposium</i> , vol. 567, 1999, pp. 343-348.				
Examiner Signature	PHAT X. CAO			Date Considered	5/9/05	

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